

DAC1403D160

Dual 14 bits DAC, up to 160 MHz, 2 x interpolating

Rev. 03 — 2 July 2012

Product data sheet

1. General description

The DAC1403D160 is optimized to reduce architecture complexity and overall system cost. It leads to dynamic performance in multi-carrier support, because of its direct IF conversion capabilities. With an internal sampling rate of up to 160 MHz, DAC1403D160 is an extremely competitive solution for broadband wireless systems transmitters, as well as a wide range of applications.

2. Features

- Dual 14-bit resolution
- Spurious-Free Dynamic Range (SFDR) = 80 dBc at 2.5 MHz
- Input data rate up to 80 MHz
- 2 × interpolation filter
- Output data rate up to 160 MHz
- Single 3.3 V power supply
- Low noise capacitor-free integrated Phase-Locked Loop (PLL)
- Low power dissipation
- HTQFP80 package
- Ambient temperature from -40 °C to +85 °C

3. Applications

- Broadband wireless systems
- Digital radio links
- Cellular base stations
- Instrumentation
- Cable modem
- Cable Modem Termination System (CMTS)/Data Over Cable Service Interface Specification (DOCSIS)

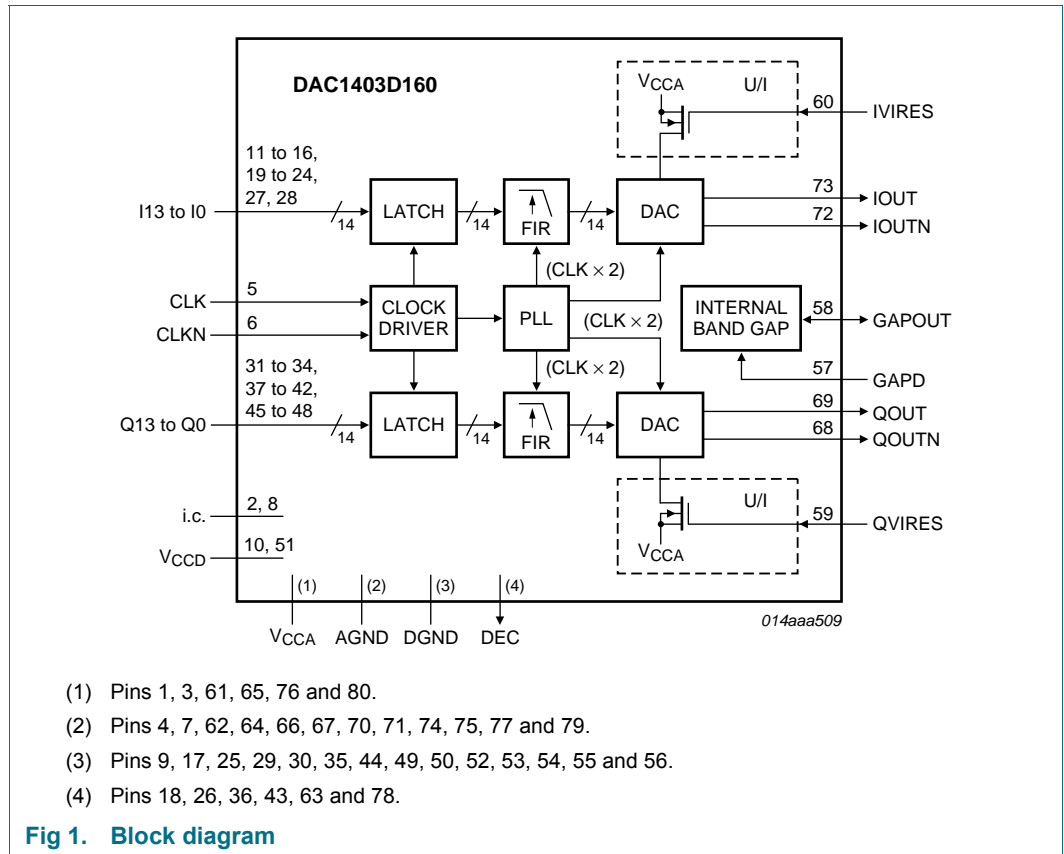


4. Ordering information

Table 1. Ordering information

| Type number | Package | | Version |
|---------------|---------|--|----------|
| | Name | Description | |
| DAC1403D160HW | HTQFP80 | plastic thermal enhanced thin quad flat package; 80 leads; body 12 × 12 × 1 mm; exposed die pad | SOT841-1 |

5. Block diagram



6. Pinning information

6.1 Pinning

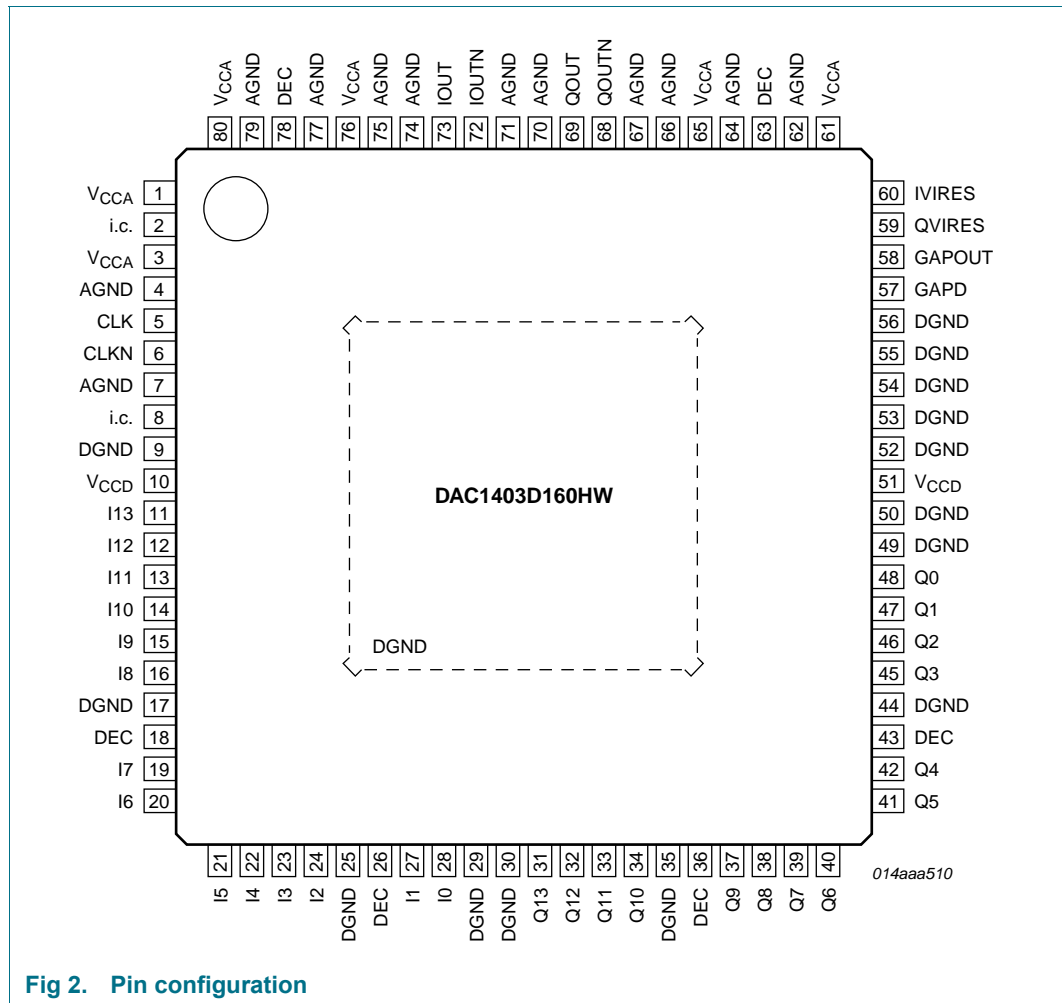


Fig 2. Pin configuration

6.2 Pin description

Table 2. Pin description

| Symbol | Pin | Type ^[1] | Description |
|------------------|-----|---------------------|----------------------------------|
| V _{CCA} | 1 | S | analog supply voltage |
| i.c. | 2 | I/O | internally connected; leave open |
| V _{CCA} | 3 | S | analog supply voltage |
| AGND | 4 | G | analog ground |
| CLK | 5 | I | clock input |
| CLKN | 6 | I | complementary clock input |
| AGND | 7 | G | analog ground |
| i.c. | 8 | O | internally connected; leave open |
| DGND | 9 | G | digital ground |

Table 2. Pin description ...continued

| Symbol | Pin | Type ^[1] | Description |
|------------------|-----|---------------------|--|
| V _{CCD} | 10 | S | digital supply voltage |
| I13 | 11 | I | I data input bit 13 (Most Significant Bit (MSB)) |
| I12 | 12 | I | I data input bit 12 |
| I11 | 13 | I | I data input bit 11 |
| I10 | 14 | I | I data input bit 10 |
| I9 | 15 | I | I data input bit 9 |
| I8 | 16 | I | I data input bit 8 |
| DGND | 17 | G | digital ground |
| DEC | 18 | O | decoupling node |
| I7 | 19 | I | I data input bit 7 |
| I6 | 20 | I | I data input bit 6 |
| I5 | 21 | I | I data input bit 5 |
| I4 | 22 | I | I data input bit 4 |
| I3 | 23 | I | I data input bit 3 |
| I2 | 24 | I | I data input bit 2 |
| DGND | 25 | G | digital ground |
| DEC | 26 | O | decoupling node |
| I1 | 27 | I | I data input bit 1 |
| I0 | 28 | I | I data input bit 0 (Least Significant Bit (LSB)) |
| DGND | 29 | G | digital ground |
| DGND | 30 | G | digital ground |
| Q13 | 31 | I | Q data input bit 13 (MSB) |
| Q12 | 32 | I | Q data input bit 12 |
| Q11 | 33 | I | Q data input bit 11 |
| Q10 | 34 | I | Q data input bit 10 |
| DGND | 35 | G | digital ground |
| DEC | 36 | O | decoupling node |
| Q9 | 37 | I | Q data input bit 9 |
| Q8 | 38 | I | Q data input bit 8 |
| Q7 | 39 | I | Q data input bit 7 |
| Q6 | 40 | I | Q data input bit 6 |
| Q5 | 41 | I | Q data input bit 5 |
| Q4 | 42 | I | Q data input bit 4 |
| DEC | 43 | O | decoupling node |
| DGND | 44 | G | digital ground |
| Q3 | 45 | I | Q data input bit 3 |
| Q2 | 46 | I | Q data input bit 2 |
| Q1 | 47 | I | Q data input bit 1 |
| Q0 | 48 | I | Q data input bit 0 (LSB) |
| DGND | 49 | G | digital ground |
| DGND | 50 | G | digital ground |

Table 2. Pin description ...continued

| Symbol | Pin | Type ^[1] | Description |
|------------------|-----|---------------------|---------------------------------------|
| V _{CCD} | 51 | S | digital supply voltage |
| DGND | 52 | G | digital ground |
| DGND | 53 | G | digital ground |
| DGND | 54 | G | digital ground |
| DGND | 55 | G | digital ground |
| DGND | 56 | G | digital ground |
| GAPD | 57 | I | internal band gap power disable input |
| GAPOUT | 58 | I/O | band gap output voltage |
| QVIRES | 59 | I | Q DAC biasing resistor |
| IVIRES | 60 | I | I DAC biasing resistor |
| V _{CCA} | 61 | S | analog supply voltage |
| AGND | 62 | G | analog ground |
| DEC | 63 | O | decoupling node |
| AGND | 64 | G | analog ground |
| V _{CCA} | 65 | S | analog supply voltage |
| AGND | 66 | G | analog ground |
| AGND | 67 | G | analog ground |
| QOUTN | 68 | O | complementary Q DAC output current |
| QOUT | 69 | O | Q DAC output current |
| AGND | 70 | G | analog ground |
| AGND | 71 | G | analog ground |
| IOUTN | 72 | O | complementary I DAC output current |
| IOUT | 73 | O | I DAC output current |
| AGND | 74 | G | analog ground |
| AGND | 75 | G | analog ground |
| V _{CCA} | 76 | S | analog supply voltage |
| AGND | 77 | G | analog ground |
| DEC | 78 | O | decoupling node |
| AGND | 79 | G | analog ground |
| V _{CCA} | 80 | S | analog supply voltage |

[1] Type description: S: Supply; G: Ground; I: Input; O: Output.

7. Functional description

The Digital-to-Analog Converter (DAC) is a segmented architecture composed of a 7-bit thermometer sub-DAC and the remaining 7-bit in a binary weighted sub-DAC.

The device produces two complementary current outputs on both channels, respectively pins IOUT/IOUTN and QOUT/QOUTN which need to be connected via a load resistor to the ground.

Figure 3 shows the equivalent analog output circuit of one DAC, which consists of a parallel combination of PMOS current sources and associated switches for each segment.

The cascade source configuration enables the increasing of the output impedance of the source and set to improve the dynamic performance of the DAC by introducing less distortion.

Figure 4 shows the internal reference configuration. In this case the bias current is given by the output of the internal regulator connected to the inverting input of the internal operational amplifiers, while external resistors R_I and R_Q are connected respectively to pins IVIRES and QVIRES. Thus the output current of the two DACs is typically fixed to 20 mA with an appropriate choice of these resistors. This configuration is optimal for temperature drift compensation because the band gap can be matched with the voltage on the feedback resistors.

The relation between full-scale output current $I_{O(fs)}$ and the R_I (R_Q) is:

$$R_I = \frac{2048 \times V_{GAPOUT}}{82 \times I_{O(fs)}} \Omega$$

The output current can also be adjusted by imposing an external reference voltage to the inverting input pin GAPOUT and disabling the internal band gap with pin GAPD set to HIGH. At a voltage lower than 1.2 V the current can be set at values lower than 20 mA. The input references at pins IVIRES and QVIRES may also be driven by separate reference voltages to adjust independently the two DAC currents.

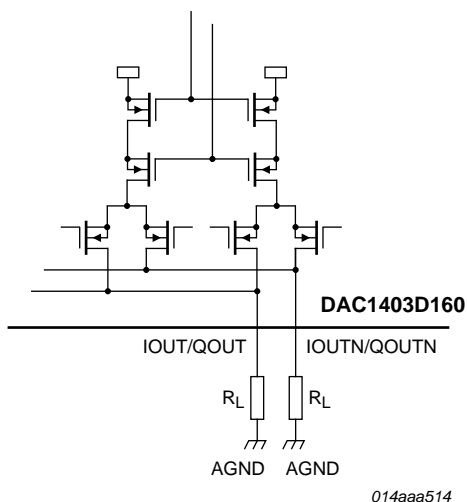


Fig 3. Equivalent analog output circuit

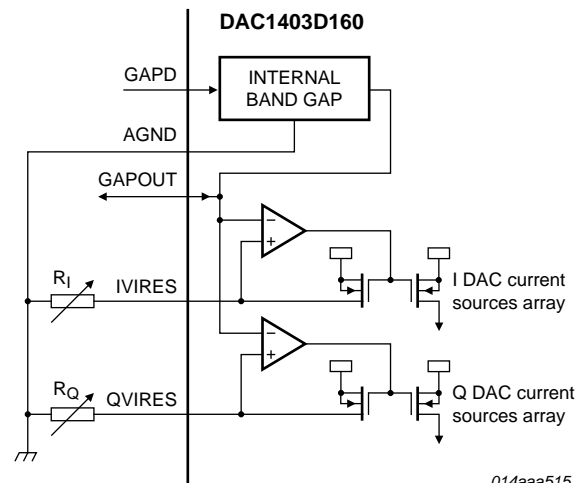


Fig 4. Internal reference configuration

8. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------------|---------------------------|---|------|-----------------|------|
| V_{CCD} | digital supply voltage | [1] | -0.3 | +3.9 | V |
| V_{CCA} | analog supply voltage | [1] | -0.3 | +3.9 | V |
| ΔV_{CC} | supply voltage difference | $V_{CCA} - V_{CCD}$ | -150 | +150 | mV |
| V_I | input voltage | pins Qn and In referenced to DGND | -0.3 | $V_{CCD} + 0.3$ | V |
| | | pins IVIRES, QVIRES and GAPD referenced to AGND | -0.3 | $V_{CCA} + 0.3$ | V |
| | | pins CLK and CLKN referenced to AGND | -0.3 | $V_{CCA} + 0.3$ | V |
| V_O | output voltage | pins IOUT, IOUTN, QOUT and QOUTN referenced to AGND | -0.3 | $V_{CCA} + 0.3$ | V |
| T_{stg} | storage temperature | | -55 | +150 | °C |
| T_{amb} | ambient temperature | | -40 | +85 | °C |
| T_j | junction temperature | | - | 125 | °C |

[1] All supplies are connected together.

9. Thermal characteristics

Table 4. Thermal characteristics

| Symbol | Parameter | Conditions | Typ | Unit |
|---------------|---|-------------|------|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | 27.1 | K/W |
| $R_{th(c-a)}$ | thermal resistance from case to ambient | in free air | 11.8 | K/W |

10. Characteristics

Table 5. Characteristics

$V_{CCD} = V_{CCA} = 3.0\text{ V to }3.6\text{ V}$; AGND and DGND connected together; $T_{amb} = -40\text{ °C to }+85\text{ °C}$; typical values measured at $V_{CCD} = V_{CCA} = 3.3\text{ V}$, $I_{O(fs)} = 20\text{ mA}$ and $T_{amb} = 25\text{ °C}$; dynamic parameters measured using output schematic given in Figure 10; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---------------|-----------|---------------|-------------------------|
| Supplies | | | | | | |
| V_{CCD} | digital supply voltage | | 3.0 | 3.3 | 3.6 | V |
| V_{CCA} | analog supply voltage | | 3.0 | 3.3 | 3.6 | V |
| I_{CCD} | digital supply current | | - | 55 | 65 | mA |
| I_{CCA} | analog supply current | | - | 73 | 85 | mA |
| P_{tot} | total power dissipation | $f_{clk} = 80\text{ MHz}$; $f_{IOUT} = f_{QOUT} = 5\text{ MHz}$ | - | 422 | 540 | mW |
| Clock inputs (CLK and CLKN) | | | | | | |
| $V_{I(cm)}$ | common-mode input voltage | | - | 1.65 | - | V |
| $V_{i(dif)(p-p)}$ | peak-to-peak differential input voltage | | - | 1.0 | - | V |
| Analog outputs (IOUT, IOUTN, QOUT and QOUTN) | | | | | | |
| $I_{O(fs)}$ | full-scale output current | differential outputs | 4 | - | 20 | mA |
| R_o | output resistance | | [1] - | 150 | - | k Ω |
| C_o | output capacitance | | [1] - | 3 | - | pF |
| Digital inputs (I0 to I13, Q0 to Q13 and GAPD) | | | | | | |
| V_{IL} | LOW-level input voltage | | DGND | - | 0.3 V_{CCD} | V |
| V_{IH} | HIGH-level input voltage | | 0.7 V_{CCD} | - | V_{CCD} | V |
| I_{IL} | LOW-level input current | $V_{IL} = 0.3\text{ }V_{CCD}$ | - | 5 | - | μA |
| I_{IH} | HIGH-level input current | $V_{IH} = 0.7\text{ }V_{CCD}$ | - | 5 | - | μA |
| Reference voltage output (GAPOUT) | | | | | | |
| V_{GAPOUT} | voltage on pin GAPOUT | | - | 1.31 | - | V |
| I_{GAPOUT} | current on pin GAPOUT | external voltage | - | 1 | - | μA |
| ΔV_{GAPOUT} | voltage variation on pin GAPOUT | | - | ± 133 | - | ppm/ $^{\circ}\text{C}$ |
| Clock timing inputs (CLK and CLKN) | | | | | | |
| f_{clk} | clock frequency | | - | - | 80 | MHz |
| $t_{w(clk)H}$ | HIGH clock pulse width | | 5 | - | - | ns |
| $t_{w(clk)L}$ | LOW clock pulse width | | 5 | - | - | ns |
| Input timing (I0 to I13 and Q0 to Q13); see Figure 5 | | | | | | |
| $t_{h(i)}$ | input hold time | | 1.1 | - | 3.4 | ns |
| $t_{su(i)}$ | input set-up time | | -1.5 | - | +0.7 | ns |
| Output timing (IOUT, IOUTN, QOUT, QOutN) | | | | | | |
| t_s | settling time | $t_o = \pm 0.5\text{ LSB}$ | [1] - | 43 | - | ns |

Table 5. Characteristics ...continued

$V_{CCD} = V_{CCA} = 3.0\text{ V}$ to 3.6 V ; AGND and DGND connected together; $T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$; typical values measured at $V_{CCD} = V_{CCA} = 3.3\text{ V}$, $I_{O(fs)} = 20\text{ mA}$ and $T_{amb} = 25\text{ }^{\circ}\text{C}$; dynamic parameters measured using output schematic given in Figure 10; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|--|------|-------------|------|------------------------|
| Digital filter specification (FIR); order N = 42; see Figure 6 and 7 and Table 7 | | | | | | |
| f_{data} | data rate | | - | - | 80 | MHz |
| $\alpha_{ripple(pb)}$ | pass-band ripple | f_{data}/f_{clk} ; 0.005 dB attenuation | - | 0.405 | - | |
| B_p | power bandwidth | f_{data}/f_{clk} ; 3 dB attenuation | - | 0.479 | - | |
| α_{stpb} | stop-band attenuation | $f_{data}/f_{clk} = 0.6$ to 1 | - | 69 | - | dB |
| $t_{d(grp)}$ | group delay time | | - | $11T_{CLK}$ | - | ns |
| Analog signal processing | | | | | | |
| Linearity | | | | | | |
| INL | integral non-linearity | | - | ± 2.9 | - | LSB |
| DNL | differential non-linearity | | - | ± 1.5 | - | LSB |
| $I_{n(o)}$ | output noise current | | - | 120 | - | pA/ $\sqrt{\text{Hz}}$ |
| E_{offset} | offset error | relative to full-scale | - | -0.3 | - | % |
| E_G | gain error | relative to full-scale | -5.4 | - | +5.4 | % |
| ΔG_{IQ} | IQ gain mismatch | between I and Q, relative to full-scale | - | ± 0.2 | - | % |
| Spurious free dynamic range | | | | | | |
| SFDR | spurious free dynamic range | $f_{clk} = 80\text{ MHz}$; BW = Nyquist | | | | |
| | | $f_o = 2.5\text{ MHz}$ at 0 dBFS | - | 80 | - | dBc |
| | | $f_o = 5\text{ MHz}$ at 0 dBFS | - | 72 | - | dBc |
| | | $f_o = 13\text{ MHz}$ at 0 dBFS | - | 64 | - | dBc |
| Harmonics | | | | | | |
| α_{2H} | second harmonic level | $f_o = 5\text{ MHz}$ | - | 73 | - | dBc |
| | | $f_o = 13\text{ MHz}$ | - | 65 | - | dBc |
| α_{3H} | third harmonic level | $f_o = 5\text{ MHz}$ | - | 88 | - | dBc |
| | | $f_o = 13\text{ MHz}$ | - | 86 | - | dBc |
| Two-tone intermodulation | | | | | | |
| IMD2 | second-order intermodulation distortion | $f_{clk} = 80\text{ MHz}$; $f_o 1 = 10\text{ MHz}$; $f_o 2 = 12\text{ MHz}$; BW = Nyquist | - | 65 | - | dBc |
| IMD3 | third-order intermodulation distortion | $f_{clk} = 80\text{ MHz}$; $f_o 1 = 10\text{ MHz}$; $f_o 2 = 12\text{ MHz}$ | - | 84 | - | dBc |
| THD | total harmonic distortion | $f_{clk} = 80\text{ MHz}$; BW = Nyquist ($T_{amb} = 25\text{ }^{\circ}\text{C}$) | | | | |
| | | $f_o = 2.5\text{ MHz}$ | - | 75 | - | dBc |
| | | $f_o = 5\text{ MHz}$ | 68 | 71 | - | dBc |
| NSD | noise spectral density | $f_{clk} = 80\text{ MHz}$ | | | | |
| | | $f_o = 2.5\text{ MHz}$ | - | -155 | - | dBm/Hz |
| | | $f_o = 5\text{ MHz}$ | - | -155 | - | dBm/Hz |
| | | $f_o = 19\text{ MHz}$ | - | -153 | - | dBm/Hz |

Table 5. Characteristics ...continued

$V_{CCD} = V_{CCA} = 3.0\text{ V to }3.6\text{ V}$; AGND and DGND connected together; $T_{amb} = -40\text{ }^{\circ}\text{C to }+85\text{ }^{\circ}\text{C}$; typical values measured at $V_{CCD} = V_{CCA} = 3.3\text{ V}$, $I_{O(fs)} = 20\text{ mA}$ and $T_{amb} = 25\text{ }^{\circ}\text{C}$; dynamic parameters measured using output schematic given in Figure 10; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------------------|------------------------------|--|-----|-----|-----|------|
| Signal-to-noise ratio | | | | | | |
| S/N | signal-to-noise ratio | $f_{clk} = 80\text{ MHz}$; BW = Nyquist | | | | |
| | | $f_o = 2.5\text{ MHz}$ | - | 80 | - | dBc |
| | | $f_o = 5\text{ MHz}$ | 70 | 80 | - | dBc |
| | | $f_o = 19\text{ MHz}$ | - | 78 | - | dBc |
| ACPR | adjacent channel power ratio | baseband; 5 MHz channel spacing; BW = 3.84 MHz | | | | |
| | | $f_o = 2.5\text{ MHz}$ | - | 69 | - | dBc |
| | | $f_o = 20\text{ MHz}$ | - | 71 | - | dBc |

[1] Guaranteed by design.

Table 6. Band gap

| Band gap disable (GAPD) | Band gap input/output (GAPOUT) | Internal band gap |
|-------------------------|--|-------------------|
| LOW | output ($V_{GAPOUT} = 1.2\text{ V}$) | enable |
| HIGH | input | disable |

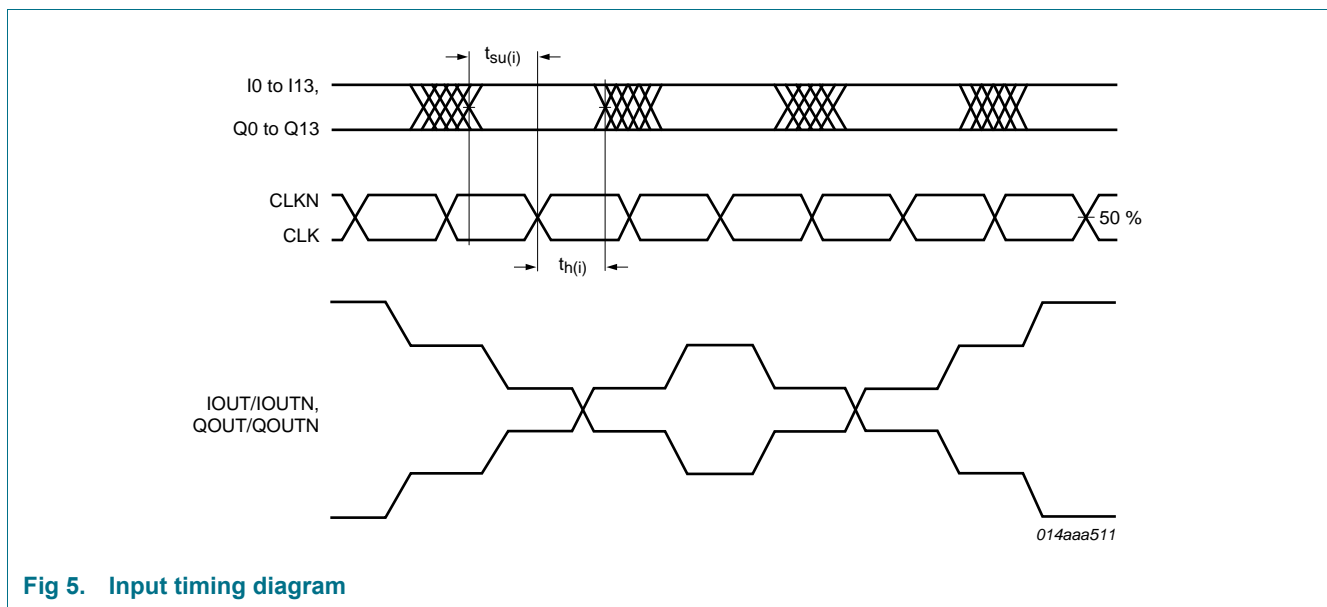


Fig 5. Input timing diagram

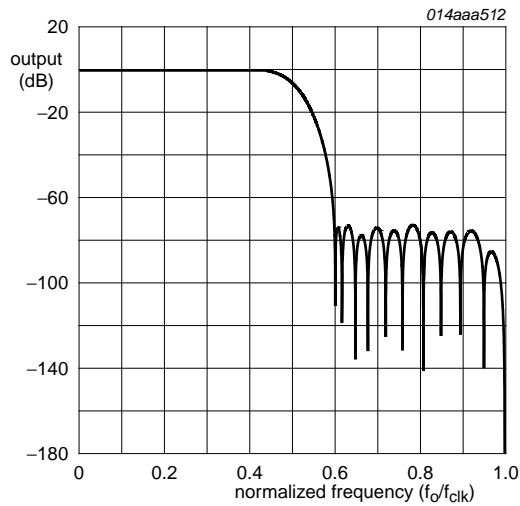


Fig 6. FIR filter frequency response

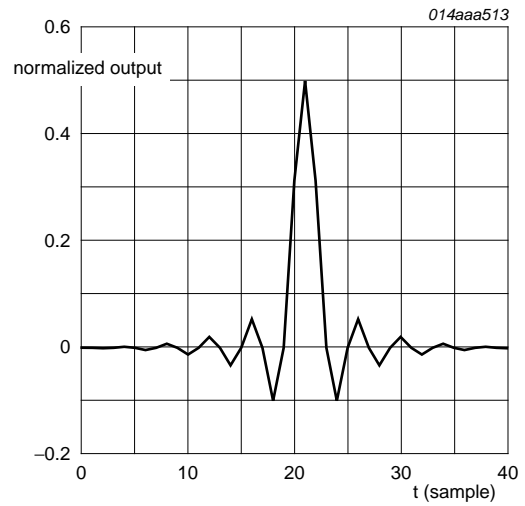


Fig 7. FIR filter impulse response

Table 7. Interpolation FIR filter coefficient

| Coefficient | Coefficient | Value |
|-------------|-------------|-------|
| H(1) | H(43) | 10 |
| H(2) | H(42) | 0 |
| H(3) | H(41) | -31 |
| H(4) | H(40) | 0 |
| H(5) | H(39) | 69 |
| H(6) | H(38) | 0 |
| H(7) | H(37) | -138 |
| H(8) | H(36) | 0 |
| H(9) | H(35) | 248 |
| H(10) | H(34) | 0 |
| H(11) | H(33) | -419 |
| H(12) | H(32) | 0 |
| H(13) | H(31) | 678 |
| H(14) | H(30) | 0 |
| H(15) | H(29) | -1083 |
| H(16) | H(28) | 0 |
| H(17) | H(27) | 1776 |
| H(18) | H(26) | 0 |
| H(19) | H(25) | -3282 |
| H(20) | H(24) | 0 |
| H(21) | H(23) | 10364 |
| H(22) | - | 16384 |

11. Application information

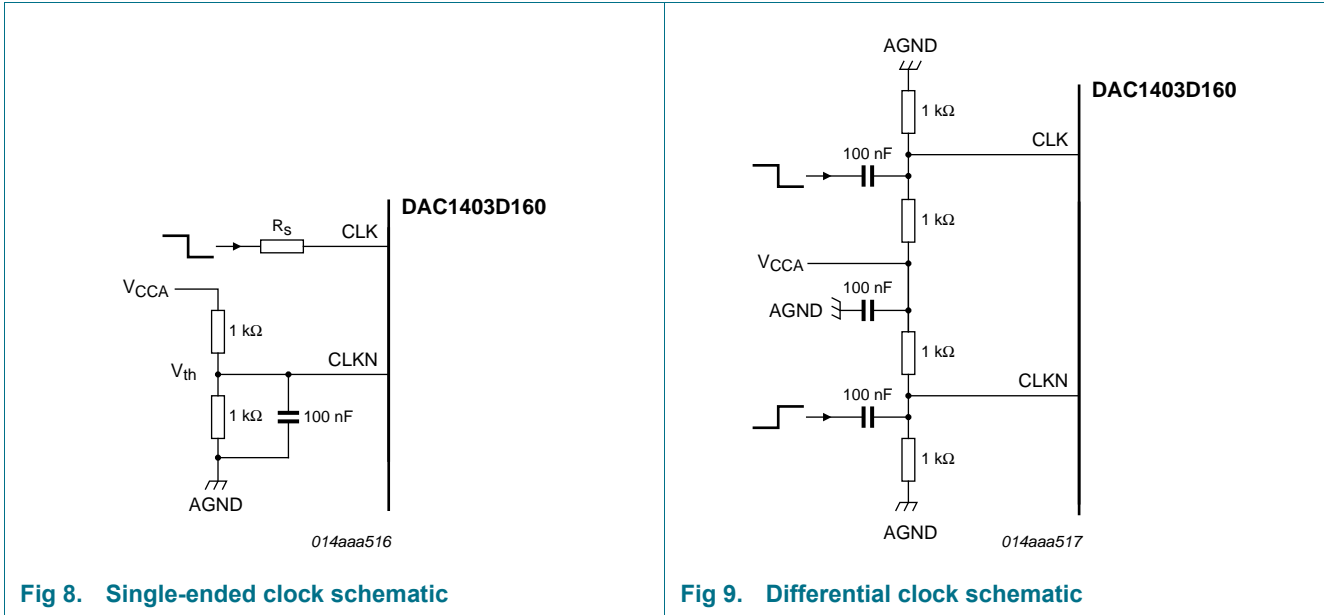
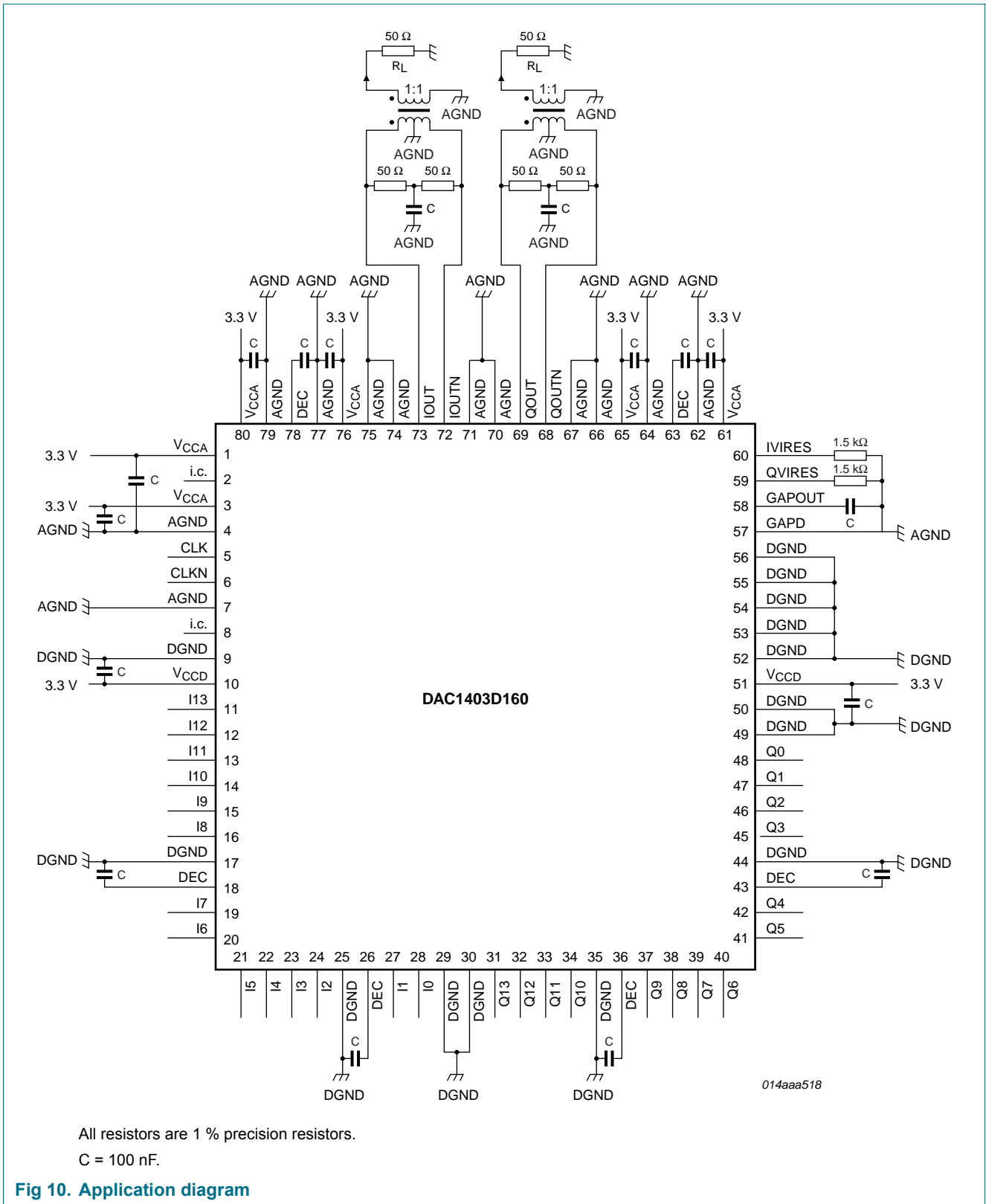


Fig 8. Single-ended clock schematic

Fig 9. Differential clock schematic



11.1 Alternative parts

The following alternative parts are also available:

Table 8. Alternative parts

| Type number | Description | | Sampling frequency |
|-------------|---|-----|--------------------|
| DAC1203D160 | Dual 12 bits DAC, with 2 × interpolating | [1] | 160 MHz |
| DAC1003D160 | Dual 10 bits DAC, with 2 × interpolating | [1] | 160 MHz |

[1] Pin to pin compatible

12. Package outline

HTQFP80: plastic thermal enhanced thin quad flat package; 80 leads; body 12 x 12 x 1 mm; exposed die pad SOT841-1

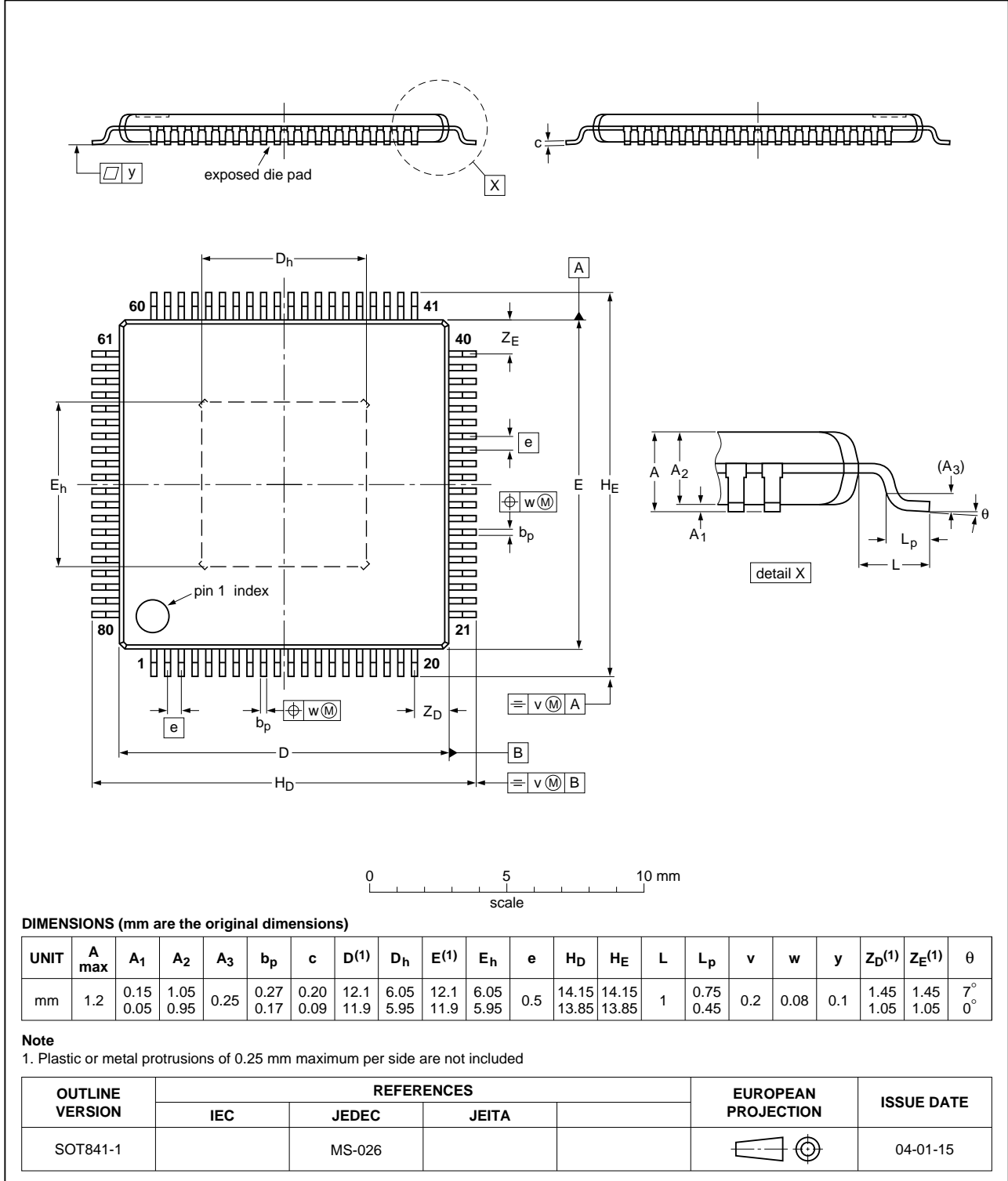


Fig 11. Package outline SOT841-1 (HTQFP80)

13. Abbreviations

Table 9. Abbreviations

| Acronym | Description |
|---------|------------------------------------|
| BW | BandWidth |
| FIR | Finite Impulse Response |
| IF | Intermediate Frequency |
| LSB | Least Significant Bit |
| MSB | Most Significant Bit |
| PLL | Phase-Locked Loop |
| PMOS | Positive-Metal Oxide Semiconductor |

14. Glossary

14.1 Static parameters

DNL — Differential Non-Linearity. The difference between the ideal and the measured output value between successive DAC codes.

INL — Integral Non-Linearity. The deviation of the transfer function from a best-fit straight line (linear regression computation).

14.2 Dynamic parameters

IMD2 — Second-order intermodulation distortion. From a dual-tone digital input sine wave (these two frequencies are close together), the intermodulation distortion product IMD2 is the ratio of the RMS value of either tone and the RMS value of the worst 2nd-order intermodulation product.

IMD3 — Third-order intermodulation distortion. From a dual-tone digital input sine wave (these two frequencies are close together), the intermodulation distortion product IMD3 is the ratio of the RMS value of either tone and the RMS value of the worst 3rd-order intermodulation product.

S/N — Signal-to-Noise ratio. The ratio of the RMS value of the reconstructed output sine wave to the RMS value of the noise excluding the harmonics and the DC component.

THD — Total Harmonic Distortion. The ratio of the RMS value of the harmonics of the output frequency to the RMS value of the output sine wave. Usually, the calculation of THD is done on the first 5 harmonics.

SFDR — Spurious-Free Dynamic Range. The ratio of the RMS value of the reconstructed output sine wave and the RMS value of the largest spurious (harmonic and non-harmonic, excluding DC component) observed in the frequency domain.

15. Revision history

Table 10. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|---|--------------------|---------------|---------------|
| DAC1403D160_3 | 20120702 | Product data sheet | - | DAC1403D160_2 |
| DAC1403D160_2 | 20080814 | Product data sheet | - | DAC1403D160_1 |
| Modifications: | <ul style="list-style-type: none">• Corrections made to row Q0 in Table 2.• Added condition & correction of value to t_s in Table 5.• Additional definition in Section 14. | | | |
| DAC1403D160_1 | 20080616 | Product data sheet | - | - |

16. Contact information

For more information or sales office addresses, please visit: <http://www.idt.com>

17. Contents

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